

View Online at <https://aerobasegroup.com/nsn/5980-01-364-5376>

General Description:

Infrared-emitting diode maximum ratings: reverse voltage: 6.0 volts; forward current: 60.0 milliamps continuous; 1.2 amps peak; 100.0 milliwatts; phototransistor: collector-emitter voltage: 30.0 volts; emitter-collector voltage: 7.0 volts; 300.0 milliwatts; operating junction temperature range: m55.0/p100.0 degrees c; dip dimensions: length: 0.320 in. Min and 0.350 in. Max; width: 0.240 in. Min and 0.260 in. Max; height: 0.115 in min and 0.200 in. Max; terminals: 6 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A23900